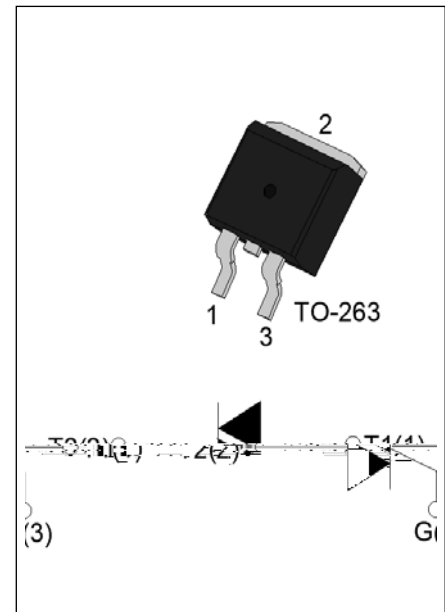


DESCRIPTION:

The JST139E-600F triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Package TO-263 is RoHS compliant.

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
V_{DRM}/V_{RRM}	600	V
$I_{GT} / / /$	25/25/25/70	mA



ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T_{stg}	-40-150	
Operating junction temperature range		T_j	-40-125	
Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$)		V_{DRM}	600	V
Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$)		V_{RRM}	600	V
RMS on-state current ($T_c = 95^\circ\text{C}$)		$I_{T(RMS)}$	16	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$, $T_j=25^\circ\text{C}$)		I_{TSM}	140	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$, $T_j=25^\circ\text{C}$)			154	
I^2t value for fusing ($t_p=10\text{ms}$, $T_j=25^\circ\text{C}$)		I^2t	98	A^2s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100\text{Hz}$, $T_j=125^\circ\text{C}$)	-	di/dt	100	A/s
	-		70	
Peak gate current ($t_p=20\text{ }\mu\text{s}$, $T_j=125^\circ\text{C}$)		I_{GM}	4	A
Average gate power dissipation ($T_j=125^\circ\text{C}$)		$P_{G(AV)}$	0.5	W
Peak gate power		P_{GM}	10	W
Peak pulse voltage ($T_j=25^\circ\text{C}$; non-repetitive, off-state; FIG.8)		V_{pp}	1	kV

ELECTRICAL CHARACTERISTICS (unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I _{GT}	V _D =12V R _L =33	- -	MAX.	25	mA
				70	

ORDERING INFORMATION

<p>J</p> <p>JieJie Microelectronics Co., Ltd.</p>	<p>ST</p> <p>Triacs</p>	<p>139</p> <p>$I_{T(RMS)}: 16A$</p>	<p>E</p> <p>E:TO-263</p>	<p>-600</p> <p>600:V_{DRM} /V_{RRM} 600V</p>	<p>F</p> <p>F:IGT1-3 25mA IGT4 70mA</p>	<p>-/</p> <p>Blank:Tube -TR:Tape & Reel</p>
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MARKING

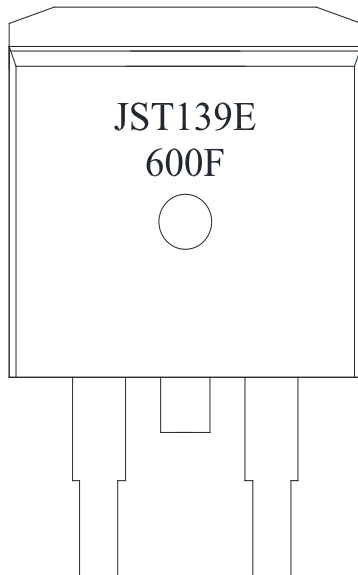


FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

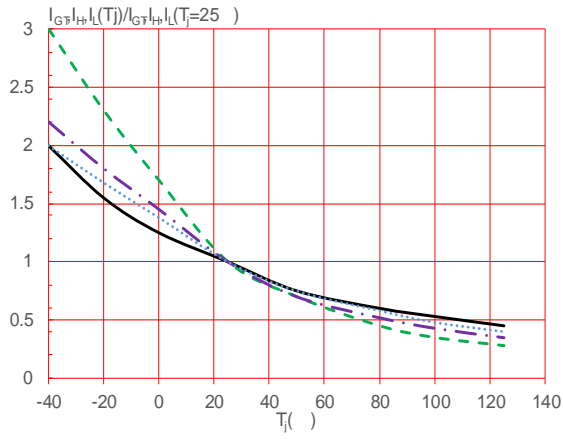
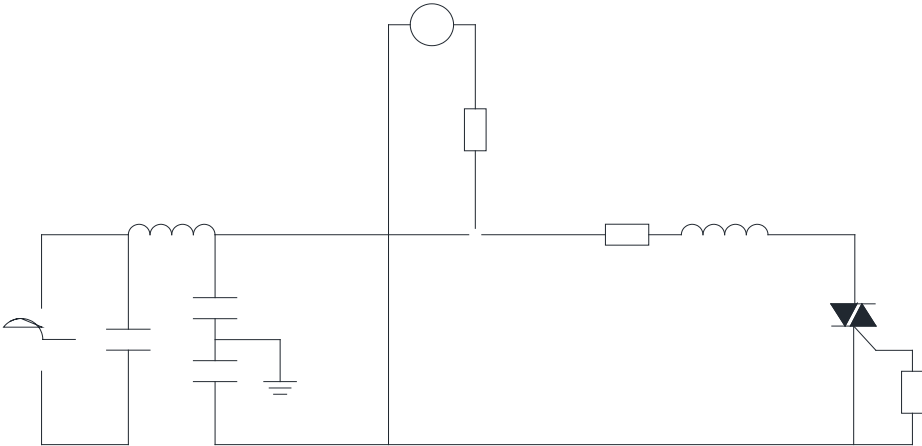


FIG.8: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



JST139E-600F

